# Progress of Nb/Cu Technology With 1.5 GHz Cavities

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- Progress with copper electropolishing
- Substrate studies
  - Angle of incidence
  - Thermal impedance
  - Aluminium cavity
- Hydrogen studies
- Conclusions

Introduction Electropolishing Substrate Hydrogen Conclusion











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Electropolishing is now performed vertically. No gas bubbles are developed since all the cell surface is polished at the plateau.

No longer problems of stabilisation time like for horizontal polishing with the cavity rotating and half-filled.

**Easier** operation

Thanks to: V. Palmieri, G. Gemme, R. Parodi









Standard 1.5 GHz cavity

**PACO** cavity

Average incidence angle of the Nb coating (0° means perpendicular). The abscissa is the length in mm along the cavity axis





The overall thermal impedance has been measured for pure Nb and Cu, and for Nb/Cu and Nb/Nb films, on 2-mm thick disks.

Cu (RRR=100) EP Cu EP + 1.5 μm Nb Nb (RRR=180) EP Nb EP + 1.5 μm Nb  $4300 \pm 200 \text{ Wm}^{-2}\text{K}^{-1}$   $4100 \pm 200 \text{ Wm}^{-2}\text{K}^{-1}$   $1200 \pm 200 \text{ Wm}^{-2}\text{K}^{-1}$  $1000 \pm 200 \text{ Wm}^{-2}\text{K}^{-1}$ 

Nb (RRR=670)(extrap.) 2500 ± 200 Wm<sup>-2</sup>K<sup>-1</sup> (Still lower than Nb/Cu, but Nb cavities performs better at high field !!)



Thanks to: G. Vandoni, J-M Rieubland, L. Dufay

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Thanks to: V. Palmieri, D. Reschke, R. Losito





Al 99.999% purity: 10X thermal conductivity of Cu at 4.2 K

Spinning + chemical polishing + coating



Thanks to: V. Palmieri, G. Lanza





The hydrogen content and its binding energy with the lattice can be measured with isosteric cycles and successive injections of known quantities of hydrogen.















In order to reduce hydrogen, a Ti underlayer has been deposited onto copper, prior to Nb deposition.

The H<sub>2</sub> equilibrium pressure has been measured, in order to verify that hydrogen is indeed reduced







- Electropolishing is well understood, and provides a solid basis for studying the physical origin of the residual resistance increase at high field.
- The angle of incidence of the coating is not an issue
- Thermal barrier between Nb and Cu is not a limitation
- Hydrogen has been decreased: no improvement of RF performance
- Intrinsic film roughness?
- NbO at the surface (preferentially at grain boundaries)?
- Nano-defects in the RF penetration depth?







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#### Standard films

#### Oxide-free films



Courtesy: P. Jacob - EMPA



An issue which is of great interest also for low-ß cavities, is the correlation between the incidence angle of the film and the residual resistance





### Digression: new ideas for low-beta cavities coating







#### Bulk Nb - EP with KEK bath

#### HPWR smoothens the grain boundaries (2001 results)